



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#4/a  
9-20-01  
Harrison

Application Serial No. . . . . RECEIVED . . . . . 09/602,395  
Filing Date . . . . . SEP 19 2001 . . . . . June 22, 2000  
Inventor . . . . . Moore, J.  
Assignee . . . . . TECHNOLOGY CENTER 2800 Micron Technology, Inc.  
Group Art Unit . . . . . 2813  
Examiner . . . . . Nguyen, T.  
Attorney's Docket No. . . . . MI22-1384  
Title: (As Amended) Methods of Forming Oxide Regions Over Semiconductor Substrates

**RESPONSE TO AUGUST 14, 2001 OFFICE ACTION**

To: BOX NON-FEE AMENDMENT  
Assistant Commissioner for Patents  
Washington, D.C. 20231

From: Jennifer J. Taylor, Ph.D. (Tel. 509-624-4276; Fax 509-838-3424)  
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**AMENDMENTS**

**In the Specification**

✓ Please replace the Title with the following new Title:

--METHODS OF FORMING OXIDE REGIONS OVER SEMICONDUCTOR SUBSTRATES--

**In the Claims**

Cancel claims 17-28.